RESEARCH PAPER

Mode matching technique-based modeling of coaxial and circular waveguide discontinuities for material characterization purposes

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In this paper, it is proposed to use a cylindrical cell for the characterization of dielectric material. The extraction of complex permittivity is based on inverse gradient approach where the full-wave simulation results are mapped to experimental data to extract the complex permittivity. As the operational frequency of radio frequency (RF)/microwave devices is increased, it becomes difficult to accurately model waveguide transitions using traditional methods based on meshing such as finite-element method (FEM) where mesh size is determined according to the wavelength. Moreover, these techniques usually require extensive computational resources. Mode matching technique (MMT) is the full-wave tool implemented in this current work. It is used to compute the generalized scattering matrices (GSMs) of the different discontinuities of test setup. These GSMs model precisely discontinuities as they include the effects of all higher-order modes propagating and evanescent. Simulation and experimental results are included to validate the proposed approach for the rigorous modeling of those discontinuities and hence the extraction of complex permittivity.

Keywords: Broadband measurements, Coaxial and circular discontinuities, Complex permittivity, Generalized scattering matrix, HFSS, Mode matching technique

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I. INTRODUCTION

Accurate modeling of waveguide discontinuities is critical to build radio frequency (RF)/microwave components. Although, it is possible to model those discontinuities using techniques based on meshed configuration like finite-element method (FEM) or finite-difference time-domain method, they require quite expensive resources and time. Thus, it becomes inappropriate to use those techniques and/or commercial softwares as design tools. The scattering parameters of waveguide discontinuities and structures composed of the cascade of these discontinuities are better characterized based on the full-wave mode matching technique (MMT). MMT is a fast-rigorous technique in which electromagnetic fields on each side of a discontinuity are expressed in terms of a complete set of orthogonal functions. The field components on both sides of the discontinuity obey the appropriate boundary conditions. The computation of scattering

parameters is straightforward when the material filling the structure is known. However, to find the complex permittivity of unknown material from measured scattering parameters becomes solving an inverse problem which requires much iteration and hence the computation is time consuming. For this purpose, MMT promptly characterizes the different discontinuities and gives their corresponding scattering. An iterative optimization gradient method is used in conjunction with MMT to compare the simulated and measured scattering parameters to extract the unknown complex permittivity. This technique has been successfully implemented and validated by extracting the complex permittivity of water and pulverized materials at room temperature over a broadband of frequencies [1, 2]. Different material characterization techniques used to extract complex permittivity are presented in [3]. Resonant methods usually offer a better accuracy yet a narrow frequency band of characterization, whereas non-resonant methods give results over a broadband. Single-port-based measurements allow the extraction of either the complex permittivity or the permeability. On the other hand, both complex permittivity and permeability can be extracted with two-port network measurements. Open-ended coaxial probe [4] is considered the easiest implementation of non-destructive measurements but the accuracy of extracted permittivity is limited to the surface roughness and the skin depth of material under test

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(MUT). Adding a shorted circular waveguide filled with MUT at the end of a coaxial line allows electromagnetic waves to propagate inside the material and also provides a better control on packing density and temperature. In [5, 6], coaxial discontinuities are analyzed based on the computation of the admittance of dominant mode in addition to the summation of contributions from higher-order modes. The computed admittance is compared to measured data from impedance analyzer and complex permittivity is extracted using an iterative method. The extraction method was limited to 18 GHz due to the usage of APC-7 mm connector. Increasing the size of the circular waveguide improves the accuracy of the method at low frequencies but puts a limit on the upper end of frequency measurement band. Published papers based on coaxial discontinuity referred to the same formulas described in [5, 6] based on impedance measurement. In this work, each discontinuity is described by its generalized scattering matrix (GSM) [7–9] obtained from full-wave MMT and compared to microwave scattering parameters measured using performance network analyzer (PNA). The accuracy of analysis comes from the consideration of all higher-order modes propagating and evanescent excited by a discontinuity. The analytical derivations of the self-inner and mutual-inner products of the coaxial-to-coaxial and coaxialto-circular discontinuities are presented. Cascading of all discontinuities is carried out to compute the reflection coefficient of the entire structure. To simplify modeling, yet without lack of accuracy, waveguide metallization is assumed to be perfect conducting and to have negligible surface roughness. Reflection coefficient computed based on mode matching is compared to those obtained based on FEM using HFSS software [10] as well as microwave measurements.

II. GEOMETRICAL DESCRIPTION OF SETUP

The test structure is presented in Fig. 1. It consists of a cylindrical waveguide shorted at one end and connected to a 1.85 mm (female (F)) to 2.4 mm (male (M)) precision adapter at the other end. For modeling purposes, the test structure is divided into three main regions. Region I, shown in Fig. 1(a), is the 2.4 mm (M) part of the precision adapter. The other side of the adapter is the 1.85 mm (F) part attached to 50- Ω coaxial cable connected to PNA at the other end. Region II is defined by the overlap volume between the 2.4 mm connector and cylindrical cell as the inner conductor of adapter protrudes inside the cell.

This region is modeled as a coaxial transmission line. Region III is the circular waveguide terminated by a short circuit. Regions II and III define the volume of cell where the MUT is inserted. The microwave circuit model of the test structure based on GSMs building blocks is given in Fig. 1(b). The model consists of the two main discontinuities: (i) coaxial 1 to coaxial 2 represented by the GSM $S^{coax-coax}$ and (ii) coaxial 2 to circular waveguide represented by $S^{coax-coax}$. The connection between the two discontinuities is a coaxial transmission line (region II) of length L_1 and characteristic impedance Z_{coax2} . The circular waveguide (region III) has a length L_2 , its characteristic impedance is Z_{circ} , and it is shorted at its end. The discontinuity interface between coaxial 1 to coaxial 2 coincides with the calibration plane, i.e., the calibration plane is right at the surface of MUT to

remove any phase ambiguity related to measured reflection coefficient.

MMT is applied to find the GSMs corresponding to the different discontinuities, transmission lines are added to account for the phase delay between discontinuities, and all blocks are cascaded to obtain the final model of the testing structure. The first step to perform MMT is to find the appropriate eigenmodes and field components in each waveguide section.

III. FULL-WAVE MODELING OF TEST STRUCTURE

A) Eigenmodes

Coaxial transmission line supports TEM, TM, and TE modes whereas circular waveguides supports only TM and TE modes. The expressions of field components inside circular waveguides and field expressions of TEM mode in coaxial waveguides are given in [11]. Expressions for TM and TE higher-order modes in coaxial waveguides are similar to those for TM and TE modes in circular waveguide with additional term including Bessel function of second kind, also called Neumann functions, to describe the fields close to the inner conductor of coaxial waveguide. The expressions of electric and magnetic field components in coaxial line for the different modes are given in the appendix. Within the context of this paper, the superscript numbers in parentheses refer to the respective waveguide region shown in Fig. 1 or Fig. 2.

B) Generalized scattering matrices

Once all field components and eigenmodes are derived for coaxial and circular waveguides, field matching is applied at each discontinuity. Figure 2 represents a general discontinuity between two waveguide regions with different cross sections. The incident and reflected waves in each region are defined in the figure where wave propagation is assumed to be along *z*-axis.

On each side of discontinuity, total transverse electric and magnetic fields are expressed as the summation of incident and reflected field components. Matching the total magnetic and electric fields on both sides of the discontinuity according to appropriate boundary conditions gives a set of equations that are solved based on the orthogonality properties of the fields.

• Continuity of tangential electric field at z = 0:

$$\sum_{j=1}^{1} (a_j^{(2)} + b_j^{(2)}) \stackrel{?}{e}_j^{(2)}(r, \phi)
= \begin{cases} \sum_{i=1}^{1} (a_i^{(1)} + b_i^{(1)}) \stackrel{?}{e}_i^{(1)}(r, \phi) & \text{on } S_1, \\ 0 & \text{on } S_2 - S_1. \end{cases} (1)$$

• Continuity of tangential magnetic field at z = 0:

$$\sum_{j=1}^{1} \left(-a_{j}^{(2)} + b_{j}^{(2)} \right) \stackrel{\rightarrow}{h}_{j}^{(2)} (r, \phi)$$

$$= \sum_{i=1}^{1} \left(a_{i}^{(1)} - b_{i}^{(1)} \right) \stackrel{\rightarrow}{h}_{i}^{(1)} (r, \phi) \text{ on } S_{1}, \tag{2}$$

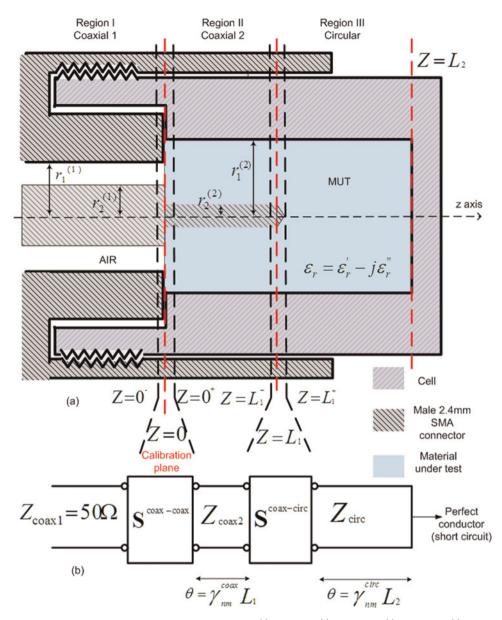


Fig. 1. (a) Schematic of the test structure. Dimensions of design parameters are: $r_1^{(1)} = 1.2$ mm, $r_2^{(1)} = 0.52$ mm, $r_1^{(2)} = 1.26$ mm, $r_2^{(2)} = 0.254$ mm, $L_1 = 1.1$ mm, and $L_2 = 5$ mm. (b) Microwave circuit model of test structure based on GSMs building blocks.

where $(\stackrel{\rightarrow}{e_i}^{(k)},\stackrel{\rightarrow}{h_i}^{(k)})$ are the tangential electric and magnetic fields of the *i*th mode in *k*th region with $k \in \{1, 2\}$ and $(a_i^{(k)}, b_i^{(k)})$ represents the corresponding field coefficients of

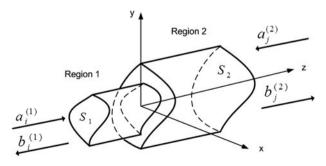


Fig. 2. Cross section of a general discontinuity: S_1 is the input smaller cross section of region 1 and S_2 represents the output larger cross section of region 2. $(a_i^{(k)}, b_i^{(k)})$ represent the incident and reflected field coefficients in k^{th} region with $k \in \{1, 2\}$.

incident and reflected waves. S1 refers to the cross section area of region 1 whereas S_2 represents the cross section area of region 2 as shown in Fig. 2. Theoretically, the fields in each region should be described as the summation of infinite number of modes; however, practically it is necessary to truncate the number of modes in each region. I modes are considered for region 2 and I modes for region 1. Equations (1) and (2) are solved by using the orthogonality properties of the electric and magnetic fields. The electric field continuity equation is tested on both sides by the magnetic field intensity of the larger cross section of region 2. The magnetic field continuity equation is tested on both sides by the electric field intensity of region 1. Hence, the incident and reflected coefficients of fields in regions I and II are related through the following two matrix equations:

$$\lambda^{(2)}(a^{(2)}+b^{(2)}) = M(a^{(1)}+b^{(1)}), \tag{3}$$

$$\mathbf{M}^{\mathsf{t}}(-a^{(2)}+b^{(2)}) = \lambda^{(1)}(a^{(1)}-b^{(1)}), \tag{4}$$

where vectors $\boldsymbol{a}^{(1)}$ and $\boldsymbol{b}^{(1)} \in \mathbb{C}^{I \times 1}$, $\boldsymbol{a}^{(2)}$ and $\boldsymbol{b}^{(2)} \in \mathbb{C}^{J \times 1}$ represent the incident and reflected field coefficients in regions I and II shown in Fig. 2. The matrix $\boldsymbol{\lambda}^{(2)} \in \mathbb{C}^{J \times J}$ represents the matrix of self-inner products for region 2 and its elements are given as

$$\int_{S_{i}} \vec{e}_{j}^{(2)}(r, \phi) \times \vec{h}_{j}^{(2)}(r, \phi) . r \, dr \, d\phi \, \hat{a}_{z} = \lambda_{jj}^{(2)}, \qquad (5)$$

where $j \in \{1, 2, ..., J\}$ and \hat{a}_z is the unit vector. $\mathbf{M} \in \mathbb{C}^{J \times I}$ is the matrix of mutual inner products between regions 1 and 2

$$\int_{S_{i}} \overrightarrow{e}_{i}^{(1)}(r,\phi) \times \overrightarrow{h}_{j}^{(2)}(r,\phi) . r \, dr \, d\phi \, \hat{a}_{z} = M_{ji}. \tag{6}$$

The matrix $\mathbf{M}^t \in \mathbb{C}^{I \times I}$, the superscript "t" denotes the transpose of matrix. The diagonal matrix $\mathbf{\lambda}^{(1)} \in \mathbb{C}^{I \times I}$ is the self inner product of region 1 and its elements are given as

$$\int_{S_{i}} \overrightarrow{e}_{i}^{(1)}(r,\phi) \times \overrightarrow{h}_{i}^{(1)}(r,\phi).r \, dr \, d\phi \, \hat{a}_{z} = \lambda_{ii}^{(1)}, \qquad (7)$$

where $i \in \{1, 2, ..., I\}$.

The GSM modeling the discontinuity between regions 1 and 2 in Fig. 2 is obtained by rearranging (1) and (2):

$$\begin{bmatrix} \boldsymbol{b}^{(1)} \\ \boldsymbol{b}^{(2)} \end{bmatrix} = \begin{bmatrix} \mathbf{S}_{11} & \mathbf{S}_{12} \\ \mathbf{S}_{21} & \mathbf{S}_{22} \end{bmatrix} \begin{bmatrix} \boldsymbol{a}^{(1)} \\ \boldsymbol{a}^{(2)} \end{bmatrix}, \tag{8}$$

where

$$\mathbf{S}_{11} = (\mathbf{U} + \mathbf{R}\mathbf{T})^{-1}(\mathbf{U} - \mathbf{R}\mathbf{T}) \quad \in C^{I \times I},$$

$$\mathbf{S}_{12} = (\mathbf{U} + \mathbf{R}\mathbf{T})^{-1}2\mathbf{R} \quad \in C^{I \times I},$$

$$\mathbf{S}_{21} = (\mathbf{U} + \mathbf{T}\mathbf{R})^{-1}2\mathbf{T} \quad \in C^{J \times I},$$

$$\mathbf{S}_{22} = (\mathbf{U} + \mathbf{T}\mathbf{R})^{-1}(\mathbf{T}\mathbf{R} - \mathbf{U}) \quad \in C^{J \times J},$$

$$(9)$$

 $\mathbf{R} \in \mathbb{C}^{I \times J}$, $\mathbf{T} \in \mathbb{C}^{J \times I}$ are defined as $\mathbf{R} = \mathbf{\lambda}^{(1)^{-1}} \mathbf{M}^t$ and $\mathbf{T} = \mathbf{\lambda}^{(2)^{-1}} \mathbf{M}$. U is the identity matrix.

It is noted that this is a general formulation describing a discontinuity between any two waveguides with different cross sections.

C) Coaxial-to-coaxial discontinuity

Hence, the problem is resumed to perform the self and mutual inner products in each region, respectively. Region 1 is a coaxial 50- Ω filled with air whereas region 2 corresponding to the probe of the 2.4 mm male part of the adapter which can also be approximated by a coaxial waveguide filled with dielectric material and different dimensions.

SELF-INNER PRODUCT

The analytical calculations can speed up if the recurrence relations of Bessel functions are used. Self-inner products for a coaxial waveguide are given below:

$$\lambda^{(i)TEM-TEM} = 2\pi \frac{k^{(i)}}{\omega \mu} \ln \left(\frac{r_1^{(i)}}{r_2^{(i)}} \right)$$
 (10)

 $\lambda_{nmnm'}^{(i)TM-TM}$

(5)
$$= \begin{cases} E \varepsilon^{(i)} \left\{ I_1 \atop I_2 \right\} \left\{ r_1^{(i)^2} \left[Z_{n+1}^2 \left(k_{c_{nm}}^{(i)TM} r_1^{(i)} \right) \right] & m = m' \text{ and } n = n' \\ - r_2^{(i)^2} \left[Z_{n+1}^2 \left(k_{c_{nm}}^{(i)TM} r_2^{(i)} \right) \right], \\ o, & m \neq m' \text{ or } n \neq n' \end{cases}$$
(11)

$$\lambda_{nmm'}^{(i)TE-TE} = \begin{cases} E\mu^{(i)} \left\{ I_1 \atop I_2 \right\} \left[r_1^{(i)^2} F Z_n^2 \left(k_{c_{nm}}^{(i)TE} r_1^{(i)} \right) & m = m' \text{ and } n = n' \\ -r_2^{(i)^2} G Z_n^2 \left(k_{c_{nm}}^{(i)TE} r_2^{(i)} \right) \right] \\ \text{o,} & m \neq m' \text{ or } n \neq n' \end{cases}$$
(12)

where
$$E = \frac{1}{2} \frac{\gamma_{nm}^{(1)TM/TE}}{k_{c_{nm}}^{2(1)TM/TE}} j\omega$$
, $F = \left(1 - \frac{n^2}{k_{c_{nm}}^{2(i)TE} r_1^{(1)^2}}\right)$,
$$G = \left(1 - \frac{n^2}{k_{c_{nm}}^{2(i)TE} r_2^{(1)^2}}\right)$$
,

i = 1, 2 to describe region 1 or 2,

$$I_{1} = \begin{cases} 2\pi & n = n' = 0, \\ \pi, & n = n' \neq 0 \text{ for PEW}, \\ 0, & n \neq n', \end{cases}$$

$$I_{2} = \begin{cases} 0, & n = n' = 0, \\ \pi, & n = n' \neq 0 \text{ for PMW}, \\ 0, & n \neq n'. \end{cases}$$

 $\varepsilon^{(i)}$ and $\mu^{(i)}$ are permittivity and permeability, respectively, in region i. It should be noted that there is no coupling between modes due to the assumption of perfect conducting boundary conditions and the orthogonality properties of the Bessel, sine, and cosine functions. The outer and inner radii of the coaxial in region i are, respectively, denoted as $r_1^{(i)}$ and $r_2^{(i)}$, where $i \in \{1,2\}$ refers to region 1 or 2, respectively as shown in Fig. 1. The cutoff constants are expressed as $k_{c_{nm}}^{(i)TM}$ for TM_{nm} modes, $k_{c_{nm}}^{(i)TE}$ for TE_{nm} modes, and $k^{(i)}$ for TEM modes as derived in the appendix. Similarly, the propagation constant for the TM_{nm} and TE_{nm} are expressed as $\gamma_{nm}^{(i)TM}$ and $\gamma_{nm}^{(i)TE}$.

MUTUAL INNER PRODUCT

The mutual inner product computation follows exactly the same procedure applied for the calculation of the self-inner product. All possible combinations between the three existing modes in coaxial waveguides are studied. However, the orthogonality properties in addition to the boundary conditions have considerably simplified the calculation and only four cases are possible. Here is the summary of the results for the

derivation of the mutual inner product concerning the coaxial-to-coaxial discontinuity. Analytical analysis shows that the incident TEM fundamental mode in region 1 only couples with TEM fundamental mode and TM_{om} higher-order modes in region 2:

$$M^{TEM(1)-TEM(2)} = 2\pi \frac{k}{\omega \mu} \ln \left(\frac{r_1^{(1)}}{r_2^{(1)}} \right),$$
 (13)

 $M_{nm}^{TEM(1)-TM(2)}$

$$= \begin{cases} -\frac{j\omega\varepsilon^{(2)}}{k_{c_{om}}^{2TM(2)}} {J_1 \brace J_2} \Big[Z_0 \Big(k_{c_{om}}^{TM(2)} r_1^{(1)} \Big) \\ -Z_0 \Big(k_{c_{om}}^{TM(2)} r_2^{(1)} \Big) \Big], & n = 0, \quad \forall m \\ 0, & n \neq 0, \quad \forall m \end{cases}$$
(14)

Finally, the mutual inner products of higher order modes are expressed as follows:

$$\begin{split} M_{nm,n'm'}^{TM(1)-TM(2)} &= \begin{cases} -j\omega \varepsilon^{(2)} \frac{\gamma_{nm}^{TM(1)}}{k_{c_{nm}}^{TM(1)}} \left\{ \begin{matrix} I_1 \\ I_2 \end{matrix} \right\} H \, Z_n \\ \left(k_{c_{n'm'}}^{TM(2)} r_2^{(1)} \right) \, Z_{n+1} \left(k_{c_{nm}}^{TM(1)} r_2^{(1)} \right) \right], & n = n', \quad \forall m, m' \\ & \text{o}, & n \neq n', \quad \forall m, m' \end{cases} \end{split}$$

$$M_{nm,n'm'}^{TE(1)-TE(2)}$$

$$= \begin{cases} -j\omega\mu^{(1)} \frac{\gamma_{n'm'}^{TE(2)}}{k_{c_{n'm'}}^{TE(2)}} \begin{Bmatrix} I_1 \\ I_2 \end{Bmatrix} HZ'_n \\ (k_{c_{nm}}^{TE(2)} r_2^{(1)}) Z_n (k_{c_{nm}}^{TE(1)} r_2^{(1)}) \end{bmatrix}, \quad n = n', \quad \forall m, m' \\ 0, \qquad n \neq n', \quad \forall m, m' \end{cases}$$
(16)

where

$$J_{1} = \begin{cases} 0, & n \neq 0 \\ 2\pi, & n = 0 \end{cases}$$
 for PEW,
$$J_{2} = \begin{cases} 0, & n \neq 0 \\ 0, & n = 0 \end{cases}$$
 for PMW,

and

$$H = \frac{r_2^{(1)}}{k_{c_{nm}}^{2TM/TE(1)} - k_{c_{n'm'}}^{2TM/TE(2)}}.$$

Concerning the TM and TE higher-order modes only coupling with same order n can be possible due to the orthogonality properties of the sine and cosine functions, independently of the order m. The derivation of the mutual and self-inner products gives the GSMs which describe the coaxial to coaxial discontinuity. By following the same process, the rigorous calculation of the self and mutual inner product of the coaxial to circular discontinuity is performed.

D) Coaxial-to-circular discontinuity

The results are similar to the previous derived solutions because the first kind and the second kind of the Bessel functions have same properties. As explained in the previous section, the difference between fields in a coaxial waveguide and circular waveguides is the added term of Bessel function second kind that describes the field around the inner conductor of coaxial line.

1) SELF INNER PRODUCT

Self-inner products for a circular waveguide are given below:

$$\lambda_{nm,n'm'}^{(s)TM-1M} = \begin{cases} j\omega \varepsilon^{(3)} \frac{\gamma_{nm}^{TM}}{k_{c_{nm}}^{2^{TM}}} \begin{Bmatrix} I_1 \\ I_2 \end{Bmatrix} \frac{r_1^{(2)^2}}{2} J_{n+1}^2 \left(k_{c_{nm}}^{TM} r_1^{(2)} \right), & n = n' \text{ and } m = m' \\ 0, & n \neq n' \text{ or } m \neq m' \end{cases}$$
(17)

$$\lambda_{nm,n'm'}^{(3)TE-TE}$$

$$-j\omega\mu^{(3)}\frac{\gamma_{nm}^{TE}}{\sum_{j=1}^{TE}}\left\{ I_{1} \right\} \frac{r_{1}^{(2)^{2}}}{\sum_{j=1}^{TE}}$$

$$= \begin{cases} -j\omega\mu^{(3)} \frac{\gamma_{nm}^{TE}}{k_{c_{nm}}^{2TE}} \begin{cases} I_1 \\ I_2 \end{cases} \frac{r_1^{(2)^2}}{2} & n = n', \text{ and } m = m' \\ \left(1 - \frac{n^2}{k_{c_{nm}}^{2TE}} r_1^{(2)^2}\right) J_n^2 \left(k_{c_{nm}}^{TE} r_1^{(2)}\right), & \\ 0, & n \neq n', \text{ or } m = m' \end{cases}$$
(18)

2) MUTUAL INNER PRODUCT

$$M_{nm}^{TEM(2)-TM(3)} = \begin{cases} \frac{j\omega\varepsilon^{(3)}}{k_{c_{om}}^{2^{TM(3)}}} \begin{cases} J_1 \\ J_2 \end{cases} J_o\left(k_{c_{om}}^{TM(3)}r_2^{(2)}\right), & n = 0, \forall m \end{cases}$$

$$0 \qquad n \neq 0, \forall m$$
(19)

$$\begin{split} M_{nm,n'm'}^{TM(2)-TM(3)} &= \begin{cases} j\omega \varepsilon^{(3)} \frac{\gamma_{nm}^{TM(2)}}{k_{c_{nm}}^{TM(2)}} \begin{Bmatrix} I_1 \\ I_2 \end{Bmatrix} KJ_n & n = n', \, \forall m, \, m' \\ \left(k_{c_{n'm'}}^{TM(3)} r_2^{(2)}\right) Z_{n+1} \left(k_{c_{nm}}^{TM(2)} r_2^{(2)}\right), & n \neq n', \, \forall m, \, m' \end{cases} \end{split}$$

$$\begin{split} M_{nm,n'm'}^{TE(2)-TE(3)} \\ &= \begin{cases} -j\omega\mu^{(1)} \frac{\gamma_{nm}^{TE(3)}}{k_{c_{nm}}^{TE(3)}} \left\{ \begin{matrix} I_1 \\ I_2 \end{matrix} \right\} KJ_n' \\ \left(k_{c_{n'm'}}^{TE(3)} r_2^{(2)} \right) Z_n \left(k_{c_{nm}}^{TE(2)} r_2^{(2)} \right), \\ 0, & n \neq n', \forall m, m' \end{cases} \end{aligned}$$

where

$$K = \frac{r_2^{(2)}}{k_{c_{nm}}^{2TM/TE(2)} - k_{c_{n',n'}}^{2TM/TE(3)}}$$

and $r_1^{(2)}$ and $r_2^{(2)}$ describe, respectively, the radius of the outer and inner conductors of the coaxial line in region 2 shown in Fig. 1(a). TM and TE higher-order modes only couple with the same order n and m due to the approximation on the perfect conducting wall and the orthogonality properties of the Bessel, sine, and cosine functions. This derivation concludes the calculation of the coaxial-coaxial and coaxial-circular discontinuities. By matching the modes at the interface between the different transitions, we have modeled and computed the corresponding GSMs: $S^{coax-coax}$ from coaxial 1 to coaxial 2 and Scoax-circ from coaxial 2 to circular waveguide as indicating in Fig. 1. So, the next step is to cascade the building blocks by introducing the coaxial transmission line of length L_1 and the circular transmission line of length L_2 to model the entire testing structure.

E) Cascading GSMs

As shown in Fig. 3, the problem can be seen as cascaded matrices separated by transmission lines. The following derivation is a general formulation and can be easily applied for any number of discontinuities.

As presented in Section B, vectors a and b represent the amplitude of the respective incident and reflected fields according to their modes. One important fact is that the order of the modes inside each GSM block should be consistent all along the calculation as follows:

$$S_{ij} = \begin{bmatrix} TEM & o & o \\ o & TM & o \\ o & o & TE \end{bmatrix}.$$

The block scattering matrices can be expressed as:

$$S^{A} = \begin{bmatrix} S_{11}^{A} & S_{12}^{A} \\ S_{21}^{A} & S_{22}^{A} \end{bmatrix}, \quad S^{B} = \begin{bmatrix} S_{11}^{B} & S_{12}^{B} \\ S_{21}^{B} & S_{22}^{B} \end{bmatrix}.$$

Reflected field coefficients are related to the incident field coefficients as follows:

$$\begin{split} b_1 &= S_{11}^A a_1 - S_{12}^A a_2, \\ b_2 &= S_{21}^A a_1 - S_{22}^A a_2, \\ b_3 &= S_{11}^B a_3 - S_{12}^B a_4, \\ b_4 &= S_{21}^B a_3 - S_{22}^B a_4. \end{split} \tag{22}$$

In the region between the two discontinuities, transmitted and reflected fields are continuous which allows us to write the following equalities:

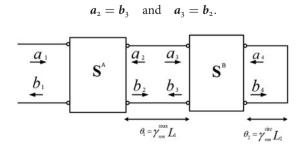


Fig. 3. Cascade of two GSMs.

At the plane of short circuit at the end of the structure:

$$a_4 = -b_4$$
.

By substituting and rearranging the previous system of equation, we have:

$$\begin{split} a_2 &= (U - S_{11}^B S_{22}^A)^{-1} (S_{11}^B S_{21}^A a_1 + S_{12}^B a_4), \\ a_3 &= (U - S_{22}^A S_{11}^B)^{-1} (S_{21}^A a_1 + S_{22}^A S_{12}^B a_4). \end{split} \tag{23}$$

where U is the identity matrix. Transmission lines are introduced in between the discontinuities to account for the proper phase shift. The first transmission line between the two discontinuities is described by the diagonal matrix:

$$\mathbf{T}_{1} = \begin{bmatrix} e^{-r_{nm}^{i}L_{1}} & \dots & \mathbf{0} \\ \vdots & \ddots & \vdots \\ \mathbf{0} & \dots & e^{-r_{nm}^{i}L_{1}} \end{bmatrix}, \tag{24}$$

where r_{nm}^{i} is the propagation constant corresponding to the ith mode and L_1 is the distance between the two discontinuities as presented in Fig. 1. The second transmission line between the second discontinuity and the short circuit is described by the following diagonal matrix:

$$\mathbf{T}_{2} = \begin{bmatrix} e^{-2r_{nm}^{i}L_{2}} & \dots & 0 \\ \vdots & \ddots & \vdots \\ 0 & \dots & e^{-2r_{nm}^{i}L_{2}} \end{bmatrix}, \tag{25}$$

where L_2 is the length between the short circuit and discontinuity plane between coaxial 2 and circular waveguide.

The submatrices of the resultant cascaded matrices are:

$$\begin{split} S_{11}^{C} &= S_{11}^{A} + S_{12}^{A} T_{1} (U - S_{11}^{B} T_{1} S_{22}^{A} T_{1})^{-1} S_{11}^{B} T_{1} S_{21}^{A}, \\ S_{12}^{C} &= S_{12}^{A} T_{1} (U - S_{11}^{B} T_{1} S_{22}^{A} T_{1})^{-1} S_{12}^{B}, \\ S_{21}^{C} &= S_{21}^{B} (U - T_{1} S_{22}^{A} T_{1} S_{11}^{B})^{-1} T_{1} S_{21}^{A}, \\ S_{22}^{C} &= S_{22}^{B} + S_{21}^{B} (U - T_{1} S_{22}^{A} T_{1} S_{11}^{B})^{-1} T_{1} S_{22}^{A} T_{1} S_{12}^{B}. \end{split} \tag{26}$$

The reflection coefficient of shorted structure is given as:

$$S_{11}^{short} = S_{11}^{C} - S_{12}^{C} T_{2} (U - T_{2} S_{22}^{C})^{-1} S_{21}^{C}.$$
 (27)

The general formulation of these cascaded matrices is applied to all the discontinuities existing in the structure. The number of modes selected to model each discontinuity has to be sufficient to ensure numerical convergence meanwhile minimizing computational time.

IV. NUMERICAL RESULTS

From the theoretical formulation of mode matching in previous section, it is observed that the theoretical required number of modes is infinite; however, for practical numerical computations, the number of modes is truncated. To determine the appropriate number of modes to be used in calculation, it is important to investigate the numerical convergence of scattering parameters versus the number of modes in each waveguide region. It is noted that the derivation

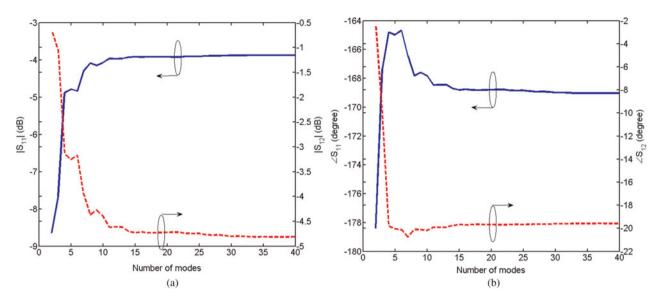


Fig. 4. Convergence of the reflection and transmission scattering parameters of a coaxial–coaxial discontinuity versus the number of modes in each side at 40 GHz: (a) magnitude S_{11} and S_{12} in dB and (b) phase S_{11} and S_{12} in degree. Dimensions of design parameters shown in Fig. 1(a) are: $r_1^{(1)} = 1.2$ mm, $r_2^{(2)} = 0.52$ mm, $r_1^{(2)} = 1.26$ mm, $r_2^{(2)} = 0.254$ mm, and $\varepsilon_r = 17 - j1.7$.

carried out in the previous section show that TM_{om} modes are only excited through the different regions. In-house program code is developed in Matlab [14] to carry out all computations presented in this work.

The convergence of the scattering parameters of the discontinuity from coaxial 1 to coaxial 2 is given in Fig. 4. The number of modes in each region is the same and the modes considered are the fundamental TEM and TM_{om} higher-order modes. The convergence results are reported at the highest frequency of 40 GHz. In this case, coaxial 1 is a 50- Ω air-filled coaxial line, representing the 2.4 mm male part of the adapter. Coaxial 2 corresponds to a coaxial line with a larger cross section and filled with a fictive dielectric material of relative complex permittivity $\varepsilon_r = 17 - j1.7$. It is observed that 15 modes result in satisfactory convergence for the studied case. We choose to use a fictive relative high complex permittivity to verify the validity of the code for

lossy materials and to compare our results with a commercial software HFSS using the FEM. Figure 5 shows the comparison of the reflection and transmission coefficients for the coaxial 1 to coaxial 2 discontinuity with 15 modes used in modeling.

Figure 5 shows clearly that the results of scattering parameters obtained from MMT and HFSS are in very good agreement. The convergence studies at 40 GHz of the discontinuity between coaxial 2 and circular waveguide are presented in Fig. 6. In this case, coaxial 2 is also filled with the dielectric material of complex permittivity $\varepsilon_r = 17 - j1.7$. The circular waveguide has the same radius as the outer radius of coaxial 2 as shown in Fig. 1(a) and it is filled with the same dielectric material. It is observed that 15 modes are enough to assure that the scattering parameters are within acceptable error.

Figure 7 presents the model used for HFSS simulation [10]. Using the appropriate planes of symmetry, it is possible to

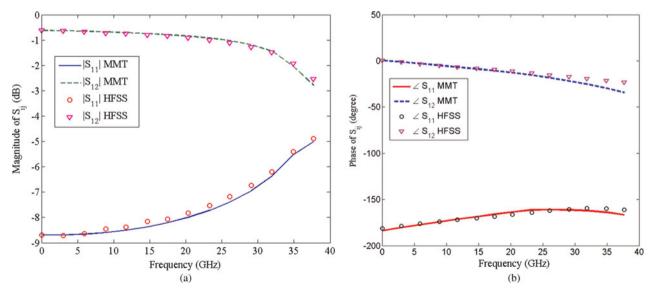


Fig. 5. Scattering parameters of the coaxial-to-coaxial discontinuity: (a) magnitude S_{ij} in dB and (b) phase S_{ij} in degree. Dimensions of design parameters shown in Fig. 1(a) $r_1^{(1)} = 1.2$ mm, $r_2^{(1)} = 0.52$ mm, $r_1^{(2)} = 0.254$ mm, and $ε_r = 17 - j1.7$.

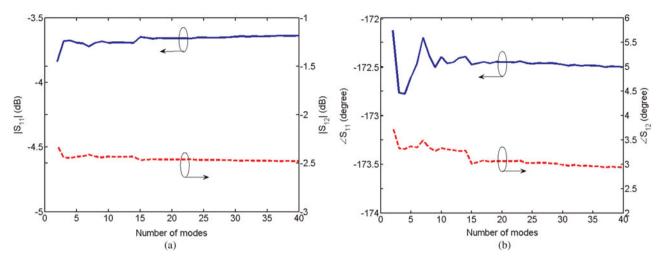


Fig. 6. Convergence of the reflection and transmission scattering parameters of a coaxial-circular discontinuity versus the number of modes in each side: (a) magnitude of S_{11} and S_{12} in dB and (b) phase of S_{11} and S_{12} in degree. Dimensions of design parameters shown in Fig. 1(a) are: $r_1^{(2)} = 1.26$ mm, $r_2^{(2)} = 0.254$ mm, and $\varepsilon_r = 17 - j1.7$.

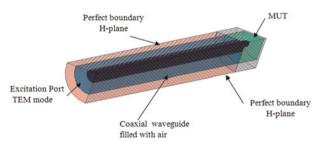


Fig. 7. HFSS model for the test structure shown in Fig. 1 (a).

simulate only one-fourth of the structure which allows increasing the number of iterations to achieve required accuracy without increasing significantly the computational time.

The HFSS and MMT simulations are carried out on a 64-bit operating system windows 7 enterprise PC with Intel® CoreTM2 Quad CPU Q9550 @2.84 GHz and 4 GB RAM memory. In HFSS, simulations are set with a

convergence criteria delta *S* of 0.001, only one excitation port TEM mode is defined sufficiently far enough from the discontinuity to avoid misinterpretation due to evanescent modes excited by the discontinuities. The number of mesh elements of the structure is 37 201 and the HFSS ComEngine memory is 66.7 M. About 12 min are sufficient to solve the model with a step frequency of 100 MHz from 10 MHz to 40 GHz.

Using the same frequency steps and limiting the number of modes based on the convergence criteria presented in Fig. 6 to 15 modes in each region, the MMT solves the same problem in 2 min on the same computer. The number of modes needs to be carefully chosen to achieve a compromise between computational time and desired accuracy. Figure 8 presents a comparison between HFSS and MMT results for the complex reflection coefficient of the actual test structure shown in Fig. 1.

From the reflection coefficient obtained from HFSS with the fictive relative complex permittivity as presented in

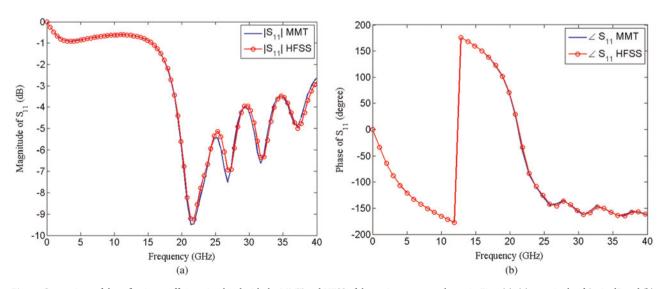


Fig. 8. Comparison of the reflection coefficient simulated with the MMT and HFSS of the testing structure shown in Fig. 1(a): (a) magnitude of S_{11} in dB and (b) phase of S_{11} in degree. Dimensions of design parameters shown in Fig. 1(a) are: $r_1^{(1)} = 1.2$ mm, $r_2^{(1)} = 0.52$ mm, $r_1^{(2)} = 1.26$ mm, $r_2^{(2)} = 0.254$ mm, $\varepsilon_r = 17 - j1.7$, $L_1 = 1.1$ mm, and $L_2 = 5$ mm.

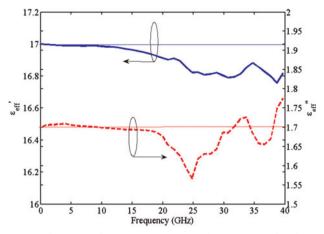


Fig. 9. Relative complex permittivity extracted using MMT based on numerical results obtained from HFSS for a fictive material ($\varepsilon_r = 17 - j_{1.7}$). The corresponding reflection coefficients are shown in Fig. 8.

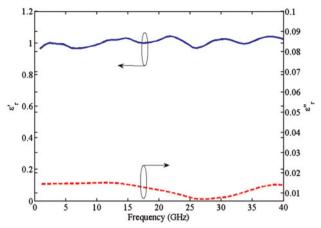


Fig. 11. Extraction of the relative complex permittivity of air when the cell is empty $(\varepsilon_r = 1 - j_0)$ computed from the measured reflection coefficient presented Fig. 10.

Fig. 8, an optimized gradient method has been implemented where both the real and imaginary parts of complex permittivity are varied until the reflection coefficient calculated from MMT comes to the one obtained from HFSS simulations. We observed a standard deviation less than 2% on the real and imaginary parts of the fictive material simulated with HFSS as shown in Fig. 9. It should be noted that the obtained reflection coefficient from HFSS plays the same role as doing microwave measurements using PNA. This step was necessary to validate the developed approach before starting real measurements.

V. EXPERIMENTAL RESULTS

The extraction of complex permittivity from measured complex reflection coefficient (S_{11}) requires the implementation of an iterative technique such as the gradient optimization method explained in [13]. The gradient technique is a general method to solve inverse problem by iteration. This technique is based on the knowledge of the distance and the

direction of the minimum from an initial value. Hence, the criteria of convergence to the actual permittivity are adjusted based on the accuracy of results extracted from PNA. Figure 10 presents the comparison between measurements and MMT results for reflection coefficient when the cell is air filled. Figure 11 shows the extracted permittivity from the measured reflection coefficient presented Fig. 10. The results are in good agreement with the theoretical value of air $(\varepsilon_r = 1 - j0)$. The fact is with such lossless material like air, the method of extraction is limited to the calibration precision related to phase measurement, specifically at low frequencies. To achieve accurate measurements over a broadband of frequencies, the calibration of the PNA is carried out over two frequency ranges: (i) from 10 MHz to 20 GHz and (ii) from 20 GHz to 40 GHz. The SOLT (short, open, load, and thru) calibration is adopted and 201 frequency points are considered in each frequency range. The intermediate frequency bandwidth is set to 70 Hz to ensure reduction of calibration errors and minimization of random noise. The reference plane is in direct contact with the MUT as shown in Fig. 1 to avoid phase ambiguity. The minor phase

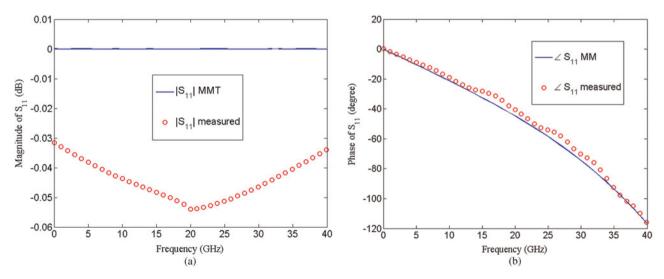


Fig. 10. Comparison of the reflection coefficient obtained from MMT and microwave measurements of the testing structure shown in Fig. 1(a) when the cell is air filled ($\varepsilon_r = 1 - jo$): (a) magnitude S_{11} in dB and (b) phase S_{11} in degree. Dimensions of design parameters as shown in Fig. 1(a) $r_1^{(1)} = 1.2$ mm, $r_2^{(1)} = 0.52$ mm, $r_1^{(2)} = 1.26$ mm, $r_2^{(2)} = 0.254$ mm, $r_1^{(2)} = 0.254$ mm, $r_2^{(2)} = 0.25$

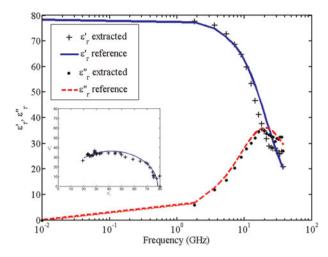


Fig. 12. Relative complex permittivity of water extracted by applying the described process in this paper and compared with data found in [15] for distilled water at 25°C.

fluctuations observed in Fig. 10(b) are due to the surface roughness of metallization which has been neglected in our modeling, tolerance of manufactured structure that degrades the extraction of the complex permittivity. However, we have proven that with this method we can extract the relative permittivity with sufficient accuracy for lossless and lossy material over wide frequency range using only a single test structure based on the numerical and experimental results [1].

To validate the technique presented in this paper, the extraction of the complex permittivity of deionized (DI) water at room temperature is shown in Fig. 12.

The frequency dependence of water complex permittivity can be modeled by Debye function:

$$\varepsilon(v) = \varepsilon(\infty) + \frac{\varepsilon(0) - \varepsilon(\infty)}{1 + j\omega\tau},$$

where the parameters of Debye relaxation spectral function for water at 25°C are given in [15]. Static dielectric constant $\varepsilon(0)=78.36\pm0.05$, permittivity at high frequency $\varepsilon(\infty)=5.2\pm0.1$, relaxation time $\tau=8.27\pm0.02$ ps, and ω is the angular frequency. The Debye relation represented by the Argand diagram (solid line) is presented in the inset and compared to our extracted measurements (black cross marker).

VI. CONCLUSIONS

The approach proposed in this paper combines accurate modeling based on full-wave technique and microwave measurements of scattering parameters. The full-wave approach that is based on MMT is implemented to derive the GSMs of all discontinuities existing in the test structure. Very good agreement between MMT simulation and measurement results is obtained. We have shown that by using the inverse problem based on the gradient optimization method concurrently with MMT, we are able to extract the complex permittivity from the measured and accurately calculated reflection coefficient. Finally, the accuracy of MMT is experimentally validated by comparing the measured refection coefficient and the extracted complex permittivity in case of air and DI water at room temperature.

APPENDIX

The expressions of field components in a coaxial transmission line are given as follows:

TEM mode:

$$e_r(r, \phi, z) = \frac{1}{r} e^{-jk_0 z},$$

 $h_{\phi}(r, \phi, z) = \frac{1}{Z_{TFM}} e_r(r, \phi, z),$ (A.1)

where the TEM wave impedance is

$$Z_{TEM} = \frac{\omega \mu}{k_0}$$
.

 TM_{nm} modes:

The solution of the Helmholtz equation gives:

$$e_{z_n}(r, \phi) = Z_n(k_c r) \begin{cases} \cos(n\phi), & \text{PEW}, \\ \sin(n\phi), & \text{PMW}, \end{cases}$$
 (A.2)

where $Z_n(k_c r) = J_n(k_c r) + G_n Y_n(k_c r)$ and the constant G_n is found by applying the boundary conditions: $e_{z_n}(r, \phi) = 0$ at $r = r_1^{(1)}$ and $r = r_2^{(1)}$. PEW and PMW denote perfect electric wall and perfect magnetic wall, respectively:

$$G_n = -\frac{J_n(k_c r_1^{(1)})}{Y_n(k_c r_1^{(1)})} = -\frac{J_n(k_c r_2^{(1)})}{Y_n(k_c r_2^{(1)})}.$$
 (A.3)

In addition, the solution of the transcendental equation allowed us to find the roots of the equation. If the *m*th roots of

$$J_n(k_c r_1^{(1)}) Y_n(k_c r_2^{(1)}) - J_n(k_c r_2^{(1)}) Y_n(k_c r_1^{(1)}) = 0$$
 (A.4)

is designated by p_{nm}^{TM} , the allowed values of k_c are $k_{c_{nm}}^{TM} = \frac{p_{nm}^{TM}}{r_1^{(1)}}$ where $n = 0, 1, 2, 3, \ldots, N$ and $m = 0, 1, 2, 3, \ldots, M$. Therefore the propagation constant can be described as

$$\gamma_{nm}^{2^{\text{TM}}} = k_{c_{nm}}^{2^{\text{TM}}} - k^2,$$
 (A.5)

where $k^2 = \omega^2 \mu \varepsilon$.

Finally, the field components for TM_{nm} higher-order modes are:

$$e_{z_{nm}}(r, \phi, z) = Z_n(k_{c_{nm}}^{TM} r) e^{-\gamma_{nm}^{TM} z} \begin{cases} \cos(n\phi), & \text{PEW}, \\ \sin(n\phi), & \text{PMW}, \end{cases}$$
(A.6)

$$h_{r_{nm}}(r, \phi, z) = \frac{jn\omega\varepsilon}{rk_{c_{nm}}^{TM}} Z_n(k_{c_{nm}}^{TM}r) e^{-\gamma_{nm}^{TM}z}$$

$$\begin{cases} -\sin(n\phi), & \text{PEW}, \\ \cos(n\phi), & \text{PMW}, \end{cases}$$
(A.7)

$$h_{\phi_{nm}}(r, \phi, z) = \frac{-j\omega\varepsilon}{k_{c_{nm}}^{TM}} Z'_n(k_{c_{nm}}^{TM} r) e^{-\gamma_{nm}^{TM} z}$$

$$\begin{cases} \cos(n\phi), & \text{PEW}, \\ \sin(n\phi), & \text{PMW}, \end{cases}$$
(A.8)

$$e_{\phi_{nm}}(r, \phi, z) = -Z_{TM}h_{r_{nm}}(r, \phi, z)$$

 $e_{r_{nm}}(r, \phi, z) = Z_{TM}h_{\phi_{nm}}(r, \phi, z)$ (A.9)
 $h_{z_{nm}}(r, \phi, z) = o$

where the wave impedance for the TM_{nm} th mode is

$$Z_{TM} = rac{\gamma_{nm}^{TM}}{j\omega\varepsilon}.$$

 TE_{nm} modes:

Similarly, the solution of the Helmholtz equation gives

$$h_{z_n}(r, \phi) = Z_n(k_c r) \begin{cases} \cos(n\phi), & \text{PEW}, \\ \sin(n\phi), & \text{PMW}, \end{cases}$$
(A.10)

where $Z_n(k_c r) = J_n(k_c r) + g_n Y_n(k_c r)$ and the constant g_n is found by applying the boundary conditions. Therefore the longitudinal component of the magnetic field must vanish at the surface conductors. Hence,

$$\frac{\partial}{\partial_r} h_{z_n}(r, \phi) \bigg|_{\substack{r = r_1^{(1)} \\ r = r_s^{(1)}}} = \frac{d}{dr} [Z_n(k_c r)] \bigg|_{\substack{r = r_1^{(1)} \\ r = r_s^{(1)}}} = 0 \tag{A.11}$$

and we get the constant

$$g_n = -\frac{J'_n(k_c r_1^{(1)})}{Y'_n(k_c r_1^{(1)})} = -\frac{J'_n(k_c r_2^{(1)})}{Y'_n(k_c r_2^{(1)})}.$$
 (A.12)

Similarly, if the mth roots of the transcendental equation

$$J'_n(k_c r_1^{(1)}) Y'_n(k_c r_2^{(1)}) - J'_n(k_c r_2^{(1)}) Y'_n(k_c r_1^{(1)}) = 0$$
 (A.13)

is designated by p_{nm}^{TE} , we find that the allowed values of k_c are $k_{c_{nm}}^{TE} = \frac{p_{nm}^{TE}}{r_s^{(1)}}$, where n = 0, 1, 2, 3, ..., N and m = 0, 1, 2, 3, ..., M.

Finally, the field components for TE_{nm} higher-order modes can be expressed as

$$h_{z_{nm}}(r, \phi, z) = Z_n(k_{c_{nm}}^{TE} r) e^{-\gamma_{nm}^{TE} z} \begin{cases} \cos(n\phi), & PEW, \\ \sin(n\phi), & PMW, \end{cases}$$
(A.14)

$$h_{r_{nm}}(r, \phi, z) = \frac{-\gamma_{nm}^{TE}}{k_{c_{nm}}^{TE}} Z'_n(k_{c_{nm}}^{TE}r) e^{-\gamma_{nm}^{TE}z} \begin{cases} \cos(n\phi), & PEW, \\ \sin(n\phi), & PMW, \end{cases}$$
(A.15)

$$h_{\phi_{nm}}(r, \phi, z) = \frac{-\gamma_{nm}^{TE}}{k_{c_{nm}}^{2^{TE}}} \frac{n}{r} Z_n(k_{c_{nm}}^{TE} r) e^{-\gamma_{nm}^{TE} z} \begin{cases} -\sin(n\phi), & PEW, \\ \cos(n\phi), & PMW, \end{cases}$$
(A.16)

$$e_{r_{nm}}(r, \phi, z) = Z_{TE}h_{r_{nm}}(r, \phi, z),$$

 $e_{\phi_{nm}}(r, \phi, z) = -Z_{TE}h_{r_{nm}}(r, \phi, z),$ (A.17)
 $e_{z_{nm}}(r, \phi, z) = 0,$

where the wave impedance for TE_{nm} th mode is

$$Z_{TE} = \frac{j\omega\mu}{\gamma_{nm}^{TE}}$$
.

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